

#### **Features**

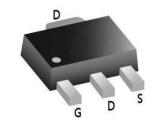
- Split Gate Trench MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low RDS(ON)

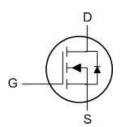
## **Product Summary**



BVDSS	RDSON	ID
100V	110mΩ	6.5 A

#### GCH, -!' @Pin Configuration





## **Applications**

- DC-DC Converters
- Power management functions
- Synchronous-rectification applications

## **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Units		
$V_{DS}$	Drain-Source Voltage	100	V		
$V_{GS}$	Gate-Source Voltage	Voltage ±20			
I <sub>D</sub> @T <sub>A</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> 6.5			
I <sub>D</sub> @T <sub>A</sub> =70°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> 3.2			
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup>	12	A		
P <sub>D</sub> @T <sub>A</sub> =25°C	Total Power Dissipation <sup>3</sup> 2		W		
T <sub>STG</sub>	Storage Temperature Range	Storage Temperature Range -55 to 150			
TJ	Operating Junction Temperature Range	-55 to 150	°C		

#### **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
Reja	Thermal Resistance Junction-ambient <sup>1</sup>		125	°C/W
R <sub>0JC</sub>	Thermal Resistance Junction-Case <sup>1</sup>		80	°C/W



## Electrical Characteristics Tc=25℃ unless otherwise specified

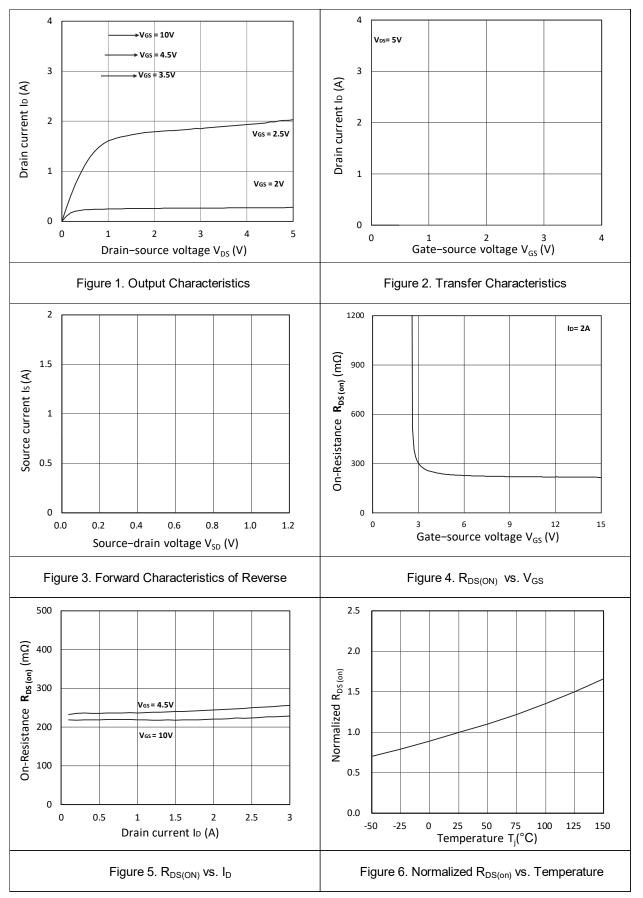
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	cteristic				•	•
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	100	110	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V	-	-	1	μA
Igss	Gate to Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±100	nA
On Chara	cteristics note3				•	•
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0	1.95	3.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance note2	V <sub>GS</sub> = 10V, I <sub>D</sub> = 3A	-	110	140	mΩ
Dynamic (	Characteristics note4		I		l	I
C <sub>iss</sub>	Input Capacitance		-	206	-	pF
Coss	Output Capacitance	$V_{DS} = 50V, V_{GS} = 0V,$	-	28.9	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1.0MHz	-	1.4	-	pF
Qg	Total Gate Charge	V <sub>DS</sub> = 50V, I <sub>D</sub> = 3A,	-	4.3	-	nC
Qgs	Gate-Source Charge		-	1.5	-	nC
Q <sub>gd</sub>	Gate-Drain("Miller") Charge	V <sub>GS</sub> = 10V	-	1.1	-	nC
Switching	Characteristics note4					
t <sub>d(on)</sub>	Turn-On Delay Time		-	14.7	-	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{DD} = 50V, I_{DS} = 3A$	-	3.5	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$R_G = 2\Omega$ , $V_{GEN} = 10V$	-	20.9	-	ns
t <sub>f</sub>	Turn-Off Fall Time		-	2.7	-	ns
Drain-Sou	rce Diode Characteristics and Maximum Rati	ngs	I.	JI.	ı	I.
Is	Maximum Continuous Drain to Source Diode Forward Current note2			-	6.5	Α
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current		-	-	12	Α
V <sub>SD</sub>	Drain to Source Diode Forward Voltage note3	V <sub>GS</sub> = 0V, I <sub>S</sub> =3A	-	-	1.3	V
t <sub>rr</sub>	Body Diode Reverse Recovery Time	\/ 0\/ 1 0A	-	32.1	-	ns
Qrr	Body Diode Reverse Recovery Time Charge	$V_{GS} = 0V, I_F = 3A,$	-	39.4	-	nC
Irrm	Peak Reverse Recovery Current	- di/dt =100A/μs	-	2.1	-	Α

#### Notes:

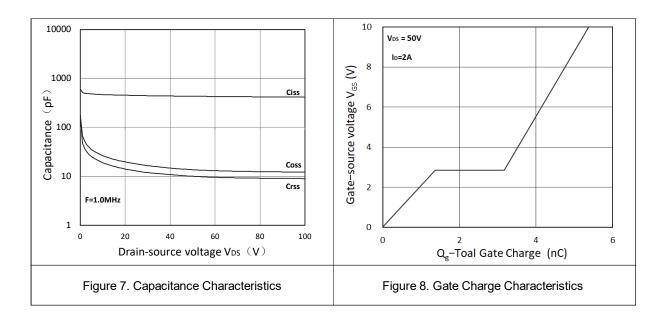
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$ 2%.
- 4. Guaranteed by design, not subject to production
- 5.  $V_{DD}{=}50$  V,  $R_{G}{=}50$   $\Omega,$  L=0.3 mH, starting  $T_{j}{=}25$   $^{\circ}C$



# **Typical Characteristics**

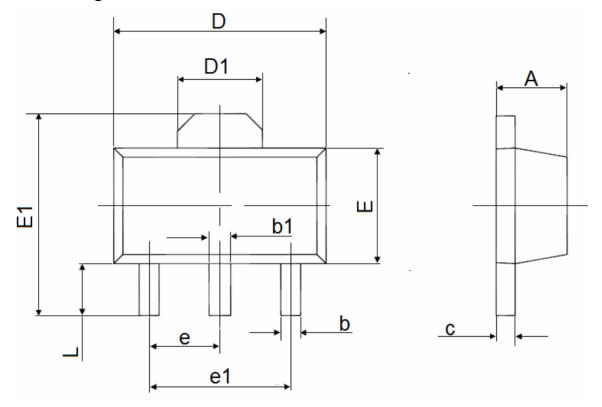








## **SOT-89-3L Package Information**



Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.400	0.580	0.016	0.023	
С	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550 REF.		0.061 REF.		
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500 TYP.		0.060 TYP.		
e1	3.000 TYP.		0.118 TYP.		
L	0.900	1.200	0.035	0.047	